

Pb Free Plating Product

MUR1620CTG/MUR1640CTG/MUR1660CTG



16.0 Ampere Heatsink Dual Common Cathode Ultra Fast Recovery Rectifiers

Features

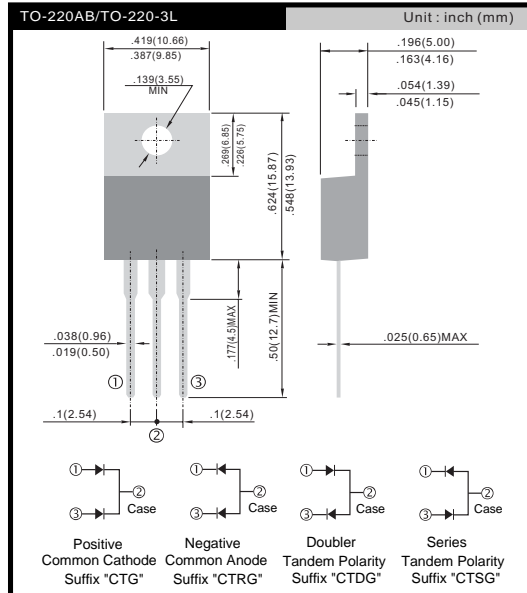
- * Fast switching for high efficiency
- * Low forward voltage drop
- * High current capability
- * Low reverse leakage current
- * High surge current capability

Application

- * Automotive Inverters and Solar Inverters
- * Plating Power Supply, SMPS and UPS
- * Car Audio Amplifiers and Sound Device Systems

Mechanical Data

- * Case: Heatsink TO-220AB open metal package
- * Epoxy: UL 94V-0 rate flame retardant
- * Terminals: Solderable per MIL-STD-202 method 208
- * Polarity: As marked on diode body
- * Mounting position: Any
- * Weight: 2.2 gram approximately

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

| | SYMBOL | MUR1620CTG | MUR1640CTG | MUR1660CTG | UNIT |
|---|----------|--------------|------------|------------|----------|
| Maximum Recurrent Peak Reverse Voltage | VRRM | 200 | 400 | 600 | V |
| Maximum RMS Voltage | VRMS | 140 | 280 | 420 | V |
| Maximum DC Blocking Voltage | VDC | 200 | 400 | 600 | V |
| Maximum Average Forward Rectified Current Tc=125 °C (Total Device 2x8A=16A) | IF(AV) | 16.0 | | | A |
| Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method) | IFSM | 175 | | | A |
| Maximum Instantaneous Forward Voltage @ 8.0 A (Per Diode/Per Leg) | VF | 0.98 | 1.3 | 1.7 | V |
| Maximum DC Reverse Current @Tj=25 °C At Rated DC Blocking Voltage @Tj=125 °C | IR | 5.0 100 | | | μA μA |
| Maximum Reverse Recovery Time (Note 1) | Trr | 35 | | | nS |
| Typical junction Capacitance (Note 2) | CJ | 90 | | | pF |
| Typical Thermal Resistance (Note 3) | RθJC | 1.5 | | | °C/W |
| Operating Junction and Storage Temperature Range | TJ, TSTG | -55 to + 150 | | | °C |

NOTES : (1) Reverse recovery test conditions IF= 0.5A, IR= 1.0A, Irr = 0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

(3) Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

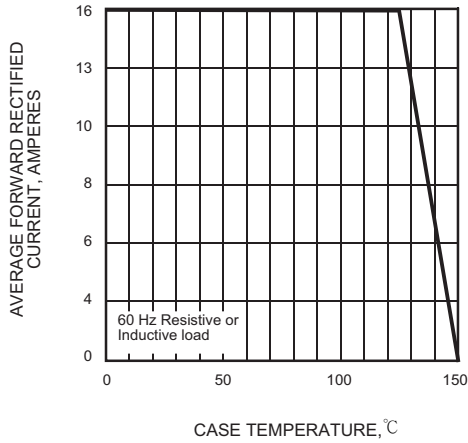


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

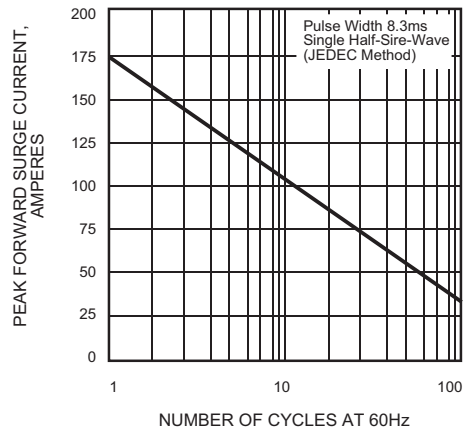


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

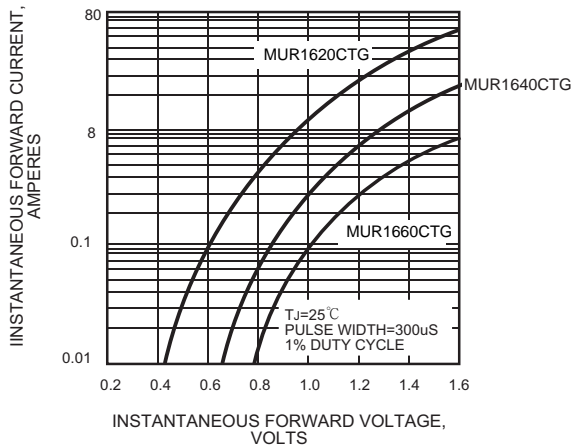


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

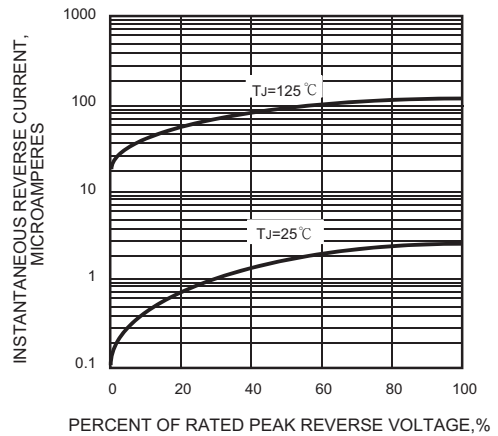


FIG.5 - TYPICAL JUNCTION CAPACITANCE

